

AIC1340

High Performance, Tripple-Ouput, Auto-Tracking Combo Controller

FEATURES

- Provide Triple Accurate Regulated Voltages
- Optimized Voltage-Mode PWM Control
- Dual N-Channel MOSFET Synchronous Drivers
- Fast Transient Response
- Adjustable Over Current Protection using R_{DS(on)}.
 No External Current Sense Resistor Required.
- Programmable Softstart Function
- 200KHz Free-Running Oscillator
- Robust Outputs Auto-Tracking Characteristics
- Sink and Source Capabilities with External Circuit

APPLICATIONS

- Advanced PC Mboards
- Information PCs
- Servers and Workstations
- Internet Appliances
- PC Add-On Cards
- DDR Termination.

GENERAL DESCRIPTION

The AIC1340 combines a synchronous voltage mode PWM controller with a low dropout linear regulator and a linear controller as well as the monitoring and protection functions in this chip. The PWM controller regulates the output voltage with a synchronous rectified step-down converter. The built-in N-Channel MOSFET drivers also help to simplify the design of step-down converter. It is able to power CPUs, GPUs, memories, and chipsets. The PWM controller features over current protection using R_{DS(on)}. It improves efficiency and saves cost, as there is no expensive current sense resistor required.

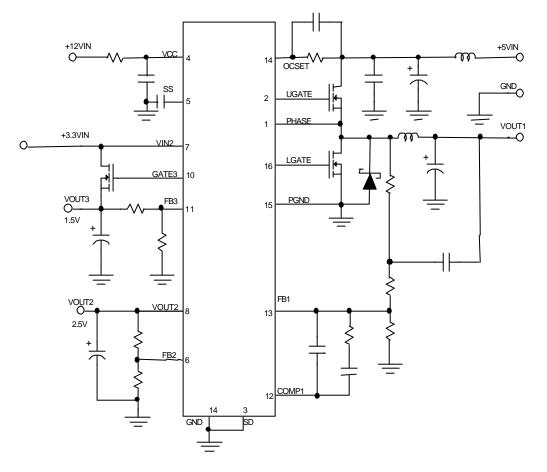
The built-in adjustable linear controller drives an external MOSFET to form a linear regulator that regulates power for system I/O. The built-in adjustable low dropout linear regulator can supply current up to 500mA for supplying another system I/O. Output voltage of both linear regulators can also be adjusted by means of the external resistor divider. Both linear regulators feature current limit. With higher load current required from the low dropout linear regulator, the AIC1341 is recommended.

The Shutdown function is also provided for disable the combo controller.

Analog Integrations Corporation www.analog.com.tw odf.dzsc.com DS-1340-00 May 24, 01



TYPICAL APPLICATION CIRCUIT



Typical Triple-Output Application

ORDERING INFORMATION

AIC1340-XX	ORDER NUMBER	PIN CONFIGURATION
PACKAGING TYPE S: SMALL OUTLINE TEMPERATURE RANGE C: 0°C~+70°C	AIC1340CS (SO16)	PHASE 16 LGATE UGATE 15 PGND SD 3 14 ocset VCC 4 13 FB1 SS 5 12 cOMP1 FB2 6 11 FB3 VIN2 7 10 GATE3 VOUT2 8 9 GND

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ABSOLUTE MAXIMUM RATING

Absolute Maximum Ratings

Supply Voltage (VCC)	15V
UGATE	GND - 0.3V to VCC + 0.3V
LGATE	GND - 0.3V to VCC + 0.3V
Input Output and I/O Voltage	GND - 0.3V to 7V

Operating Conditions

Ambient Temperature Range	0° C to 85°C
Maximum Operating Junction Temperature	100°C
Supply Voltage, VCC	15V±10%

Thermal Information

Thermal Resistance θJA (°C/W)	
SOIC Package	100°C/W
Maximum Junction Temperature (Plastic Package)	150°C
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	

TEST CIRCUIT

Refer to APPLICATION CIRCUIT.



ELECTRICAL CHARACTERISTICS (V_{cc}=12V, T_J=25°C, Unless otherwise specified)

PARAMETER	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
VCC SUPPLY CURRENT						
Supply Current	UGATE, LGATE, GATE3 and VOUT2 open	I _{cc}		1.8	3	mA
POWER ON RESET						
Rising VCC Threshold	V _{OCSET} =4.5V	VCC _{THR}	8.6	9.5	10.4	V
Falling VCC Threshold	V _{OCSET} =4.5V	VCC _{THF}	8.2	9.2	10.2	V
Rising VIN2 Under-Voltage Threshold		VIN2 _{THR}	2.5	2.6	2.7	V
VIN2 Under-Voltage Hystere- sis		VIN2 _{HYS}		130		mV
Rising V _{OCSET1} Threshold		V _{OCSETH}		1.3		V
OSCILLATOR						
Free Running Frequency		F	170	200	230	KHz
Ramp. Amplitude		ΔV_{OSC}		1.3		V_{P-P}
REFERENCE			_	-	-	
FB2 Reference Voltage		V_{REF2}	1.240	1.265	1.290	V
FB3 Reference Voltage		V_{REF3}	1.250	1.275	1.300	V
LINEAR REGULATOR						
Regulation	10mA <i<sub>0UT2<150mA</i<sub>		-1		+1	%
Under-Voltage Level	FB2 falling	$FB2_{UV}$		70	82	%
Over-Current Protection			430	570		mA
Over-Current Protection During Start-up				750		mA
LINEAR CONTROLLER						
Regulation	0 < I _{GATE3} < 10mA		-2.5		+2.5	%
Under-Voltage Level	FB3 falling	FB3 _{UV}		70	80	%



ELECTRICAL CHARACTERISTICS (Continued)

PARAMETER	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
PWM CONTROLLER ERRO	RAMPLIFIER					
DC GAIN				76		dB
Gain Bandwidth Product		GBWP		11		MHz
Slew Rate	COMP1=10pF	SR		6		V/μS
PWM CONTROLLER GATE	PWM CONTROLLER GATE DRIVER					
Upper Drive Source	VCC=12V, V _{UGATE} =11V	R_{UGH}		5.2	6.5	Ω
Upper Drive Sink	VCC=12V, V _{UGATE} =1V	R_{UGL}		3.3	5	Ω
Lower Drive Source	VCC=12V, V _{LGATE} =11V	R_{LGH}		4.1	6	Ω
Lower Drive Sink	VCC=12V, V _{LGATE} =1V	R_{LGL}		3	5	Ω
PROTECTION						
OCSET Current Source	V_{OCSET} =4.5 V_{DC}	I _{OCSET}	170	200	230	μA
Soft-Start Current		I _{SS}		11		μA
Chip Shutdown Soft Start Threshold					1.0	V

PIN DESCRIPTIONS

- Pin 1: PHASE: Over-current detection pin. Connect the PHASE pin to source of the external high-side N-MOSFET. This pin detects the voltage drop across the high-side N-MOSFET RDS(ON) for overcurrent protection.
- Pin 2: UGATE: External high-side N-MOSFET gate drive pin. Connect UGATE to gate of the external high-side N-MOSFET.
- Pin 3: SD: To shut down the system, active high or floating.
- Pin 4: VCC: The chip power supply pin. It also

provides the gate bias charge for all the MOSFETs controlled by the IC. Recommended supply voltage is 12V.

Pin 5: SS:Soft-start pin. Connect a capaci-
tor from this pin to ground. This
capacitor, along with an internal
10μA (typically) current source,
sets the soft-start interval of the
converter.

Pulling this pin low will shut down the IC.

Pin 6: FB2: Connect this pin to a resistor dvider to set the linear regulator output voltage.



Pin 7: VIN2: This pin supplies power to the internal regulator. Connect this pin to a suitable 3.3V source.

> Additionally, this pin is used to monitor the 3.3V supply. If, following a start-up cycle, the voltage drops below 2.6V (typically), the chip shuts down. A new softstart cycle is initiated upon return of the 3.3V supply above the under-voltage threshold.

- Pin 8: VOUT2: Output of the linear regulator. Supplies current up to 500mA.
- Pin 9: GND: Signal GND for IC. All voltage levels are measured with respect to this pin.
- Pin 10: GATE3: Linear Controller output drive pin. This pin can drive either a Darlington NPN transistor or a Nchannel MOSFET.
- Pin 11: FB3 Negative feedback pin for the linear controller error amplifier connect this pin to a resistor dvider to set the linear controller output voltage.
- Pin 12: COMP1 External compensation pin. This

pin is connected to error amplifier output and PWM comparator. An RC network is connected to FB1 in to compensate the voltage control feedback loop of the converter.

Pin 13: FB1 The error amplifier inverting input pin. the FB1 pin and COMP1 pin are used to compensate the voltage-control feedback loop.

Pin 14: OCSET: Current limit sense pin. Connect a resistor R_{OCSET} from this pin to the drain of the external high-side N-MOSFET. R_{OCSET}, an internal 200µA current source (I_{OCSET}), and the upper N-MOSFET onresistance (R_{DS(ON)}) set the overcurrent trip point according to the following equation:

$$I_{PEAK} = \frac{I_{OCSET} \times R_{OCSET}}{R_{DS(ON)}}$$

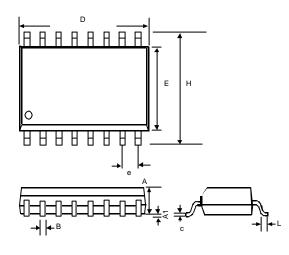
Pin 15: PGND: Driver power GND pin. PGND should be connected to a low impedance ground plane in close to lower N-MOSFET source.

Pin 16: LGATE: Lower N-MOSFET gate drive pin.



PACKAGE DIMENSIONS

• 16 LEAD PLASTIC SO (300 mil) (unit: mm)



SYMBOL	MIN	MAX	
А	2.35	2.65	
A1	0.10	0.30	
В	0.33	0.51	
С	0.23	0.32	
D	10.10	10.50	
Е	7.40	7.60	
е	1.27(TYP)		
Н	10.00	10.65	
L	0.40	1.27	